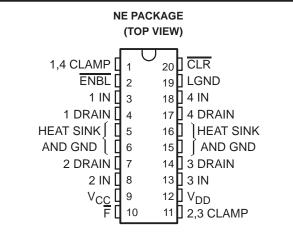
SLIS012 - D3378, FEBRUARY 1990

- Output Voltage up to 60 V
- Four Output Channels of 700-mA Nominal Current Per Channel
- Pulsed Current . . . 3 A Per Channel
- Low r_{DS(on)} . . . 0.5 Ω Typ
- Avalanche Energy . . . 50 mJ
- Thermal Shutdown Protection With Fault (Overtemperature) Output
- NE Package Designed for Heat Sinking
- Integral Output Clamp Diodes
- Input Transparent Latches for Data Storage
- Asynchronous Clear to Turn off All Outputs
- Output Parallel Capability for Increased Current Drive up to 12-A Total Pulsed Load Current

description

The TPIC2406 is a monolithic, high-voltage, high-current, quadruple power driver designed for use in systems that require high load power. The device contains built-in high-speed output clamp diodes for inductive transient protection. Power driver applications include lamps, relays, solenoids, and dc stepping motors.



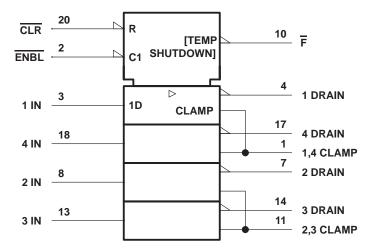
FUNCTION TABLE (each channel)

(carette caracter)						
FUNCTION	INPUTS			OUTPUT	FAULT	
FUNCTION	ENBL	CLR	IN	Υ	F	
	Х	L	Χ	Н	Н	
Normal	L	Н	L	Н	Н	
Operation	L	Н	Н	L	Н	
	Н	Н	Χ	Q ₀	Н	
Thermal Shutdown	Х	Х	Χ	Н	L	

H = high-level, L = low-level, X = irrelevant

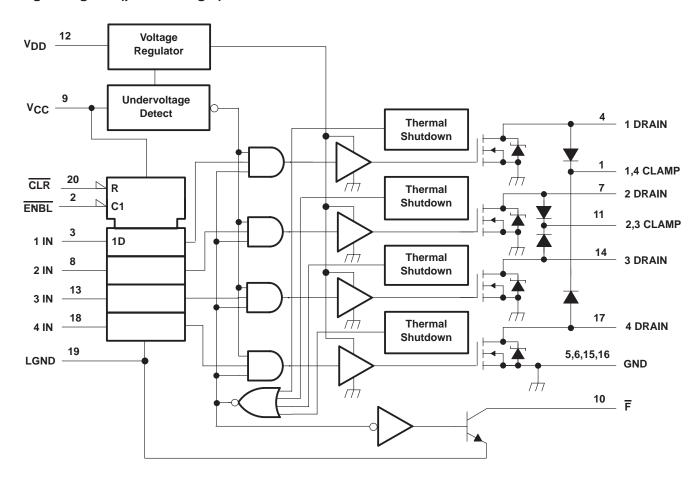
The device features four inverting open-drain outputs, each controlled by an input storage latch with common clear and enable controls. All inputs accept standard TTL- and CMOS-logic levels. The $\overline{\text{CLR}}$ function is asynchronous and turns all four outputs off regardless of data inputs. Taking $\overline{\text{ENBL}}$ low puts the input latch into a transparent mode, allowing the data inputs to affect the output. In this state, all four outputs are held off while $\overline{\text{CLR}}$ is low, but return to the stages on the data inputs when $\overline{\text{CLR}}$ goes high. When $\overline{\text{ENBL}}$ is taken high, the latch is put into a storage mode and the last state of the data inputs is held in the latches. If $\overline{\text{CLR}}$ is taken low, the data in the latches is cleared and all outputs are turned off. If $\overline{\text{CLR}}$ is taken high again, $\overline{\text{ENBL}}$ must be cycled low to read new data into the latch.

logic symbol[†]

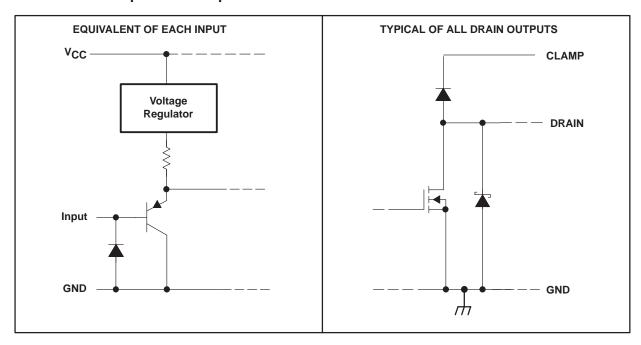


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematics of inputs and outputs



absolute maximum ratings over -40°C to 125°C case temperature range (unless otherwise noted)

Logic supply voltage, V_{CC} (see Note 1) Power MOSFET driver supply voltage, V_{DD} Logic input voltage, V_{I} Power MOSFET drain-source voltage, V_{DS} Output voltage at \overline{F} , V_{O} Clamp-diode voltage Continuous source-drain diode anode current Pulsed source-drain diode anode current Pulsed drain current, each output, all outputs on, $I_{D1} = I_{D2} = I_{D3} = I_{D4}$, $T_{A} = 25^{\circ}C$	60 V 7 V 60 V 7 V 60 V 1.25 A
(see Note 2 and Figures 5 through 8) Continuous drain current, each output, all outputs on, $I_{D1} = I_{D2} = I_{D3} = I_{D4}$, $T_A = 25^{\circ}C$. Peak drain current, single output, I_{DM} , $T_A = 25^{\circ}C$ (see Note 3) Single-pulse avalanche energy, E_{AS} . Continuous total dissipation at or below 25°C free-air temperature (see Note 4) Continuous total dissipation at or below 100°C case temperature (see Note 4) Operating junction temperature range, T_J Storage temperature range Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	770 mA 12.5 A 50 mJ 2.5 W 6 W -40°C to 150°C -40°C to 150°C

NOTES: 1. All voltage values are with respect to the five ground (GND and LGND) terminals connected together.

- 2. Pulse duration = 10 ms, duty cycle = 6%.
- 3. Pulse duration \leq 100 μ s, duty cycle \leq 2%.
- 4. For operation above 25°C free-air temperature, derate linearly at the rate of 20 mW/°C. For operation above 100°C case temperature, derate linearly at the rate of 120 mW/°C. To avoid exceeding the design maximum junction temperature, these ratings should not be exceeded. Due to variations in individual devices, electrical characteristics, and thermal resistance, the built-in thermal overload protection can be activated at power levels slightly above or below the rated dissipation.

TPIC2406 INTELLIGENT-POWER QUAD MOSFET LATCH

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recommended operating conditions

		MIN	NOM	MAX	UNIT
Logic supply voltage, V _{CC}		4.5		5.5	V
Output supply voltage, V _{DD}		10		35	V
High-level input voltage, VIH		2			V
Low-level input voltage, V _I L				0.6	V
Setup time, data before ENBL ↑, t _{Su} (see Figure 1)		100			ns
Hold time, data after ENBL ↑, th (see Figure 1)		100			ns
Dulas duration to (and Figure 4)	ENBL low	000			
Pulse duration, t _W (see Figure 1)	CLR low	300			ns
Operating case temperature, T _C		-40		125	°C

electrical characteristics, V_{CC} = 5 V, V_{DD} = 14 V, T_{C} = 25°C (unless otherwise noted)

	PARAMETER TEST		CONDITIONS†	MIN	TYP	MAX	UNIT
V(BR)DSX	Drain-source breakdown voltage	I _D = 1 mA		60			V
VF(K)	Clamp-diode forward voltage	I _F = 1.25 A,	See Notes 5 and 6			1.6	V
V _{SD}	Source-drain diode forward voltage	I _S = 1.25 A,	See Notes 5 and 6			1.5	V
VIK	Input clamp voltage	$V_{CC} = MIN,$	I _I = ~ 12 mA			-1.5	V
V _{OL}	Low-level output voltage at F	I _{OL} = 4 mA			0.4		V
lн	High-level input current	V _{CC} = 5.5 V,	V _I = 2.7 V			20	μΑ
I _I L	Low-level input current	V _{CC} = 5.5 V,	V _I = 0.4 V			0.1	mA
Icc	Logic supply current	I _O = 0,	All outputs off			10	mA
I _N	Nominal current	V _{DS(on)} = 0.5 V, See Notes 5, 6, and	$I_{N} = I_{D},$ $T_{C} = 85^{\circ}C,$ d 7		700		mA
I_{DD}	Output supply current	$I_{O} = 0$,	All outputs off			6	mA
	$V_{DS} = 55 V$,	V _O = 0			1		
I _{R(K)}	Clamp-diode reverse current	$V_{DS} = 55 V$,	$V_{O} = 0$, $T_{C} = 125^{\circ}C$			10	μΑ
	Official desire comment	V _R = 55 V				1	4
IDSX	Off-state drain current	V _R = 55 V,	T _C = 125°C			10	μΑ
I _{O(F)}	High-level fault leakage current	V _{OH} = 5.5 V				1	μΑ
		I _D = 1.25 A			0.5	0.6	
	Static drain-source on-state resistance	I _D = 1.25 A, T _C = 125°C	See Notes 5 and 6		0.8	1	Ω
		I _D = 3 A			0.55	0.65	

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTES: 5. Technique should limit T_J-T_C to 10°C maximum.

^{6.} These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.

^{7.} Nominal current is defined for a consistent comparison between devices from different sources. It is the current that produces a voltage drop of 0.5 V at 85°C case temperature.

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switching characteristics, V_{CC} = 5 V, V_{DD} = 24 V, T_{C} = 25°C

	PARAMETER	TEST CON	IDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high-level drain output from clock				450		ns
tPHL	Propagation delay time, high-to-low-level drain output from clock	C _L = 30 pF,	See Figure 1		550		ns
tTLH	Transition time, low-to-high-level of source-drain output]			35		ns
tTHL	Transition time, high-to-low-level of source-drain output				30		ns
tPLH	Propagation delay time, low-to-high-level drain output from input				380		ns
tPHL	Propagation delay time, high-to-low-level drain output from input	$C_L = 30 \text{ pF},$ $I_D = I_N = 700 \text{ mA}$	See Figure 2,		380		ns
t _r	Rise time, low-to-high-level of source-drain output	1 - '			35		ns
tf	Fall time, high-to-low-level of source-drain output				70		ns
ta	Reverse-recovery-current rise time	I _F = 3 A, See Notes 5 and 6,	di/dt = 100 A/μs, See Figure 3		45		ns

NOTES: 5. Technique should limit T_J-T_C to $10^{\circ} C$ maximum.

thermal resistance

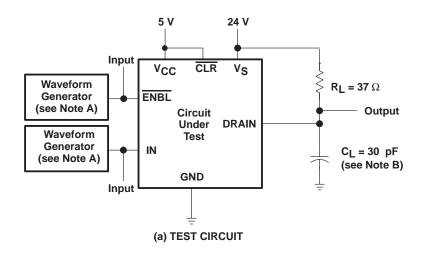
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance	All four outputs with equal power			8.33	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance	All four outputs with equal power			50	-C/VV

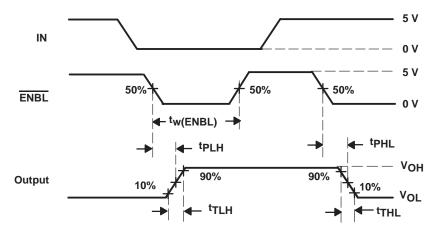
operating characteristics over -40°C to 125°C case temperature range

PARAMETER	MIN	TYP	MAX	UNIT
Undervoltage shutdown	3		4.5	V
Thermal shutdown temperature		155		°C
Thermal shutdown hysteresis		15		°C

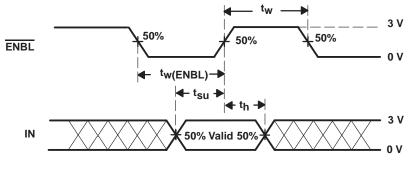
^{6.} These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.

PARAMETER MEASUREMENT INFORMATION





(b) SWITCHING TIMES FROM ENABLE INPUT



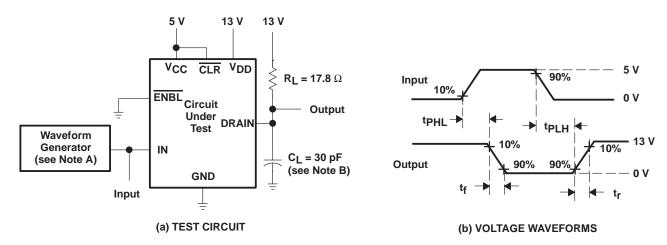
(c) INPUT SETUP AND HOLD WAVEFORMS

NOTES: A. The pulse generator has the following characteristics: $t_f \le 10$ ns, $t_f \le 10$ ns, $t_W = 300$ ns, PRR = 5 kHz, $Z_O = 50$ Ω . B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms

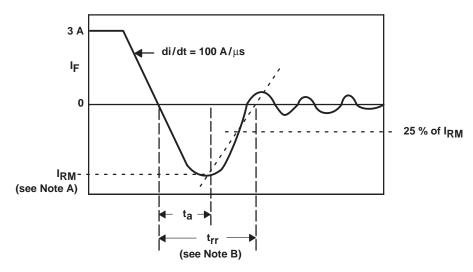


PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: $t_r \le 10$ ns, $t_f \le 10$ ns, $t_W = 5$ ms, PRR = 5 kHz, $Z_O = 50$ Ω . B. C_L includes probe and jig capacitance.

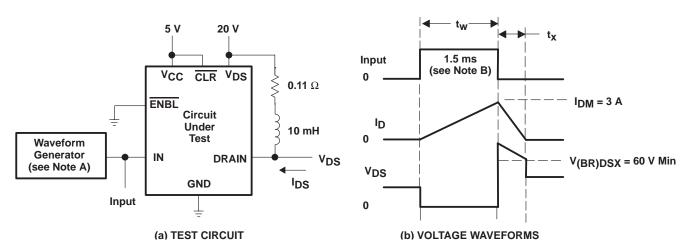
Figure 2. Test Circuit and Voltage Waveforms



NOTES: A. I_{RM} = maximum recovery current. B. t_{rr} = reverse recovery time.

Figure 3. Reverse-Recovery-Current Waveforms of Source-Drain Diode

PARAMETER MEASUREMENT INFORMATION



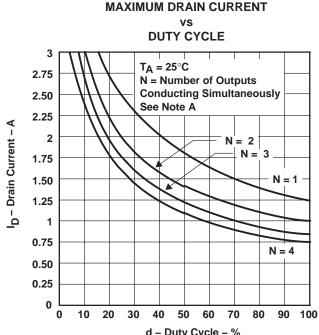
NOTES: A. The pulse generator has the following characteristics: $t_{\Gamma} \le 10$ ns, $t_{W} = 1$ ms, PRR = 5 kHz, $Z_{O} = 50~\Omega$.

B. Input pulse duration (t_W) is increased until peak current $I_{DM} = 3$ A.

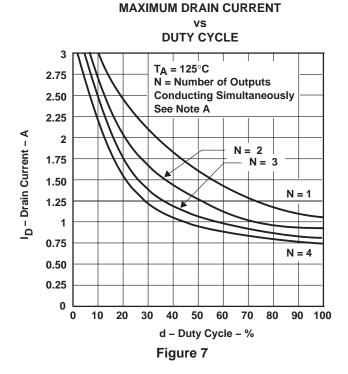
Energy test level is defined as
$$E_{AS} = \frac{I_{DM} \times V_{(BR)DSX} \times t_X}{2} = 50 \text{ mJ min.}$$

Figure 4. Single-Pulse Avalanche Energy Test Circuit and Waveforms

MAXIMUM RATINGS



d - Duty Cycle - % Figure 5



MAXIMUM DRAIN CURRENT

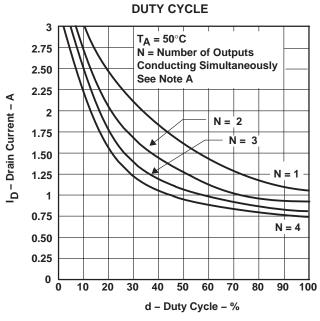


Figure 6

MAXIMUM DRAIN CURRENT

vs **PULSE DURATION**

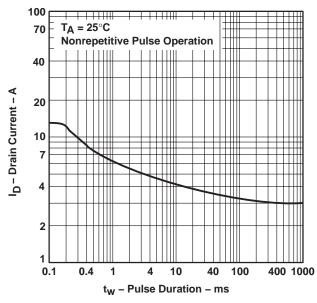
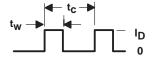


Figure 8

NOTE A: For Figures 5, 6, and 7, d = $\frac{t_W}{t_C}$ = $\frac{10 \text{ ms}}{t_C}$, where t_W and t_C are defined by the following:



MAXIMUM RATINGS

MAXIMUM CONTINUOUS DRAIN CURRENT

FREE-AIR TEMPERATURE

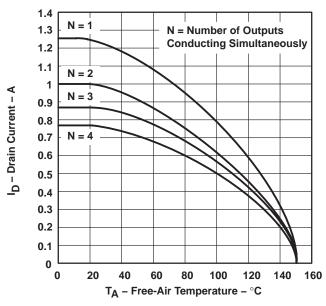
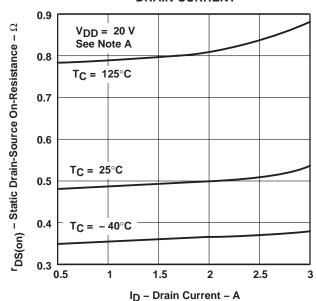


Figure 9

TYPICAL CHARACTERISTICS

STATIC DRAIN-SOURCE ON-RESISTANCE

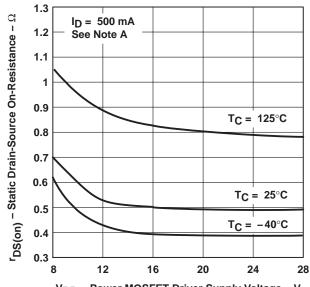
DRAIN CURRENT



NOTE A: Technique should limit $T_J - T_C$ to 10°C maximum.

STATIC DRAIN-SOURCE ON-RESISTANCE

POWER MOSFET DRIVER SUPPLY VOLTAGE



V_{DD} - Power MOSFET Driver Supply Voltage - V

Figure 10 Figure 11



THERMAL INFORMATION

FREE-AIR TEMPERATURE DISSIPATION DERATING CURVE

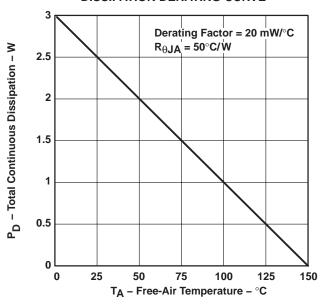
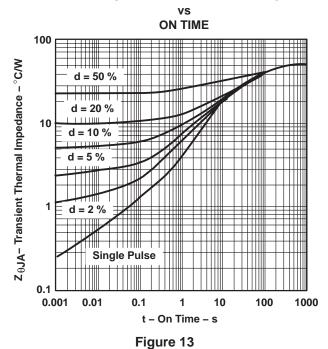


Figure 12

TRANSIENT THERMAL IMPEDANCE



The single-pulse curve in Figure 11 represents measured data. The curves for various pulse durations are based on the following equation:

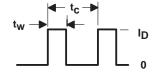
$$\begin{split} Z_{\theta_{JA}} \; &= \; \left| \frac{t_W}{t_c} \right| R_{\theta_{JA}} \; + \; \left| \; 1 \; - \; \frac{t_W}{t_c} \right| Z_{\theta(t_W} + \;_{t \; c}) \\ \\ &+ \; Z_{\theta(t_W)} \; - \; Z_{\theta(t_C)} \end{split}$$

Where:

 $Z_{\theta(t_{W}^{})} = \underset{\text{for } t = t_{W}}{\text{the single-pulse thermal impedance}}$

 $Z_{\theta(t_c)} \ = \ \text{the single-pulse thermal impedance} \\ \text{for } t = \ t_c \ \text{seconds}$

$$d = t_W/t_C$$



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